

General Description

The MAX9984 evaluation kit (EV kit) simplifies the evaluation of the MAX9984 GSM, WCDMA, and WiMAX base-station downconversion mixer. It is fully assembled and tested at the factory. Standard 50Ω SMA connectors are included on the EV kit's input and output ports to allow quick and easy evaluation on the test bench.

This document provides a list of test equipment required to evaluate the device, a straightforward test procedure to verify functionality, a description of the EV kit circuit, the circuit schematic, a bill of materials (BOM) for the kit, and artwork for each layer of the PC board.

Contact MaximDirect sales at 888-629-4642 for pricing and availability on these kits.

†Appropriate tuning is required for an RF frequency range below

815MHz (LO frequency range below 570MHz). See Tables 1 and

2 for component tuning details.

Features

- **♦ Fully Assembled and Tested**
- ♦ 400MHz to 1000MHz RF Frequency[†]
- ♦ 325MHz to 850MHz LO Frequency[†]
- ♦ 50MHz to 250MHz IF Frequency
- ♦ 8.1dB Conversion Gain
- ♦ 25dBm IIP3
- ♦ 9.3dB Noise Figure
- ♦ Integrated LO Buffer
- ♦ Switch-Selectable (SPDT), Two LO Inputs
- ♦ -3dBm to +3dBm LO Drive
- ♦ 54dB LO1 to LO2 Isolation
- ♦ 50Ω SMA Connectors on Input and Output Ports
- ♦ 4:1 Balun for Single-Ended IF Output

Ordering Information

PART	TEMP RANGE	IC PACKAGE	
MAX9984EVKIT	$T_C = -40^{\circ}C \text{ to } +85^{\circ}C^{**}$	20 Thin QFN-EP*	

^{*}EP = Exposed paddle.

Component List

815MHz to 1000MHz RF Frequency Operation

DESIGNATION	QTY	DESCRIPTION
C1	1	10pF ±5%, 50V C0G ceramic capacitor (0603) Murata GRM1885C1H100J
C2, C4, C7, C8, C10, C11, C12	7	82pF ±5%, 50V C0G ceramic capacitors (0603) Murata GRM1885C1H820J
C3, C5, C6, C9, C13, C14	6	0.01µF ±10%, 50V X7R ceramic capacitors (0603) Murata GRM188R71H103K
C15	1	220pF ±5%, 50V C0G ceramic capacitor (0402) Murata GRM1555C1H221J
J1–J4	4	PC board edge-mount SMA RF connectors (flat-tab launch) Johnson 142-0741-856

DESIGNATION	QTY	DESCRIPTION
L1, L2	2	330nH ±5% wire-wound inductors (0805) Coilcraft 0805CS-331XJBC
L3	1	47nH ±5% wire-wound inductor (0603) Coilcraft 0603CS-47NXJBC
R1	1	953Ω ±1% resistor (0603) Any
R2	1	619Ω ±1% resistor (0603) Any
R3	1	3.57Ω ±1% resistor (1206) Digi-Key 311-3.57FCT-ND
R4	1	47kΩ ±5% resistor (0603)
T1	1	4:1 transformer (200:50) Mini-Circuits TC4-1W-7A

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^{**} T_C = Case temperature.

Component List (continued)

815MHz to 1000MHz RF Frequency Operation (continued)

DESIGNATION	QTY	DESCRIPTION
TP1	1	Large test point for 0.062in PC board (red) Mouser 151-107 or equivalent
TP2	1	Large test point for 0.062in PC board (black) Mouser 151-103 or equivalent
TP3	1	Large test point for 0.062in PC board (white) Mouser 151-101 or equivalent

DESIGNATION	QTY	DESCRIPTION
U1	1	Active mixer IC (5mm x 5mm, 20-pin thin QFN, EP) Maxim MAX9984ETP NOTE: U1 HAS AN EXPOSED PADDLE CONDUCTOR THAT REQUIRES IT TO BE SOLDER ATTACHED TO A GROUNDED PAD ON THE CIRCUIT BOARD TO ENSURE A PROPER ELECTRICAL/THERMAL DESIGN.

Alternate Component List for 450MHz RF Frequency Operation

DESIGNATION	QTY	DESCRIPTION
Ср	1	7.0pF ±0.25pF, 50V C0G ceramic capacitor (0603) Murata GRM1885C1H7R0C
C1	1	56pF ±5% 50V, C0G ceramic capacitor (0603) Murata GRM1885C1H560J
C2, C4, C7, C8, C10, C11, C12	7	220pF ±5%, 50V C0G ceramic capacitors (0603) Murata GRM1885C1H221J
C3, C5, C6, C9, C13, C14	6	0.01µF ±10%, 50V X7R ceramic capacitors (0603) Murata GRM188R71H103K
C15	1	220pF ±5%, 50V C0G ceramic capacitor (0402) Murata GRM1555C1H221J
J1–J4	4	PC board edge-mount SMA RF connectors (flat-tab launch) Johnson 142-0741-856
L1, L2	2	820nH ±5% wire-wound inductors (0805) Coilcraft 0805CS-821XJBC
L3	1	47nH ±5% wire-wound inductor (0603) Coilcraft 0603CS-47NXJBC
R1	1	953Ω ±1% resistor (0603) Any

DESIGNATION	QTY	DESCRIPTION	
R2	1	619Ω ±1% resistor (0603) Any	
R3	1	3.57Ω ±1% resistor (1206) Digi-Key 311-3.57FCT-ND	
R4	1	47 k Ω ±5% resistor (0603) Any	
T1	1	4:1 transformer (200:50) Mini-Circuits TC4-1W-7A	
TP1	1	Large test point for 0.062in PC board (red) Mouser 151-107 or equivalent	
TP2	1	Large test point for 0.062in PC board (black) Mouser 151-103 or equivalent	
TP3	1	Large test point for 0.062in PC board (white) Mouser 151-101 or equivalent	
U1	1	Active mixer IC (5mm x 5mm, 20-pin thin QFN, EP) Maxim MAX9984ETP NOTE: U1 HAS AN EXPOSED PADDLE CONDUCTOR THAT REQUIRES IT TO BE SOLDER ATTACHED TO A GROUNDED PAD ON THE CIRCUIT BOARD TO ENSURE A PROPER ELECTRICAL/THERMAL DESIGN.	

Quick Start

The MAX9984 EV kit is fully assembled (per Table 1) and factory tested. Follow the instructions in the *Connections and Setup* section for proper device evaluation.

Test Equipment Required

This section lists the recommended test equipment to verify the operation of the MAX9984. It is intended as a guide only, and substitutions may be possible:

- One DC supply capable of delivering +5.0V and 300mA
- Three RF signal generators capable of delivering 10dBm of output power in the 100MHz to 3GHz frequency range (i.e., HP 8648)
- One RF spectrum analyzer with a minimum 100kHz to 3GHz frequency range (HP 8561E)
- One RF power meter (HP 437B)
- One power sensor (HP 8482A)

Connections and Setup

This section provides a step-by-step guide to testing the basic functionality of the EV kit. As a general precaution to prevent damaging the outputs by driving high-VSWR loads, do not turn on DC power or RF signal generators until all connections are made.

This procedure is specific to operation in the cellular band (815MHz to 1000MHz), low-side injected LO for a 160MHz IF. Choose the test frequency based on the particular system's frequency plan, and adjust the following procedure accordingly. See Figure 1 for the mixer test setup diagram:

- Calibrate the power meter. For safety margin, use a power sensor rated to at least +20dBm, or use padding to protect the power head as necessary.
- 2) Connect 3dB pads to the DUT ends of each of the three RF signal generators' SMA cables. This padding improves VSWR and reduces the errors due to mismatch.
- 3) Use the power meter to set the RF signal generators according to the following:
 - RF signal source: -5dBm into DUT at 910MHz (this will be approximately -2dBm before the 3dB pad).
 - LO1 signal source: 0dBm into DUT at 750MHz (this will be approximately 3dBm before the 3dB pad).
 - LO2 signal source: 0dBm into DUT at 751MHz (this will be approximately 3dBm before the 3dB pad).

- 4) Disable the signal generator outputs.
- 5) Connect the RF source (with pad) to RFIN.
- 6) Connect the LO1 and LO2 signal sources to the EV kit LO input.
- 7) Measure loss in 3dB pad and cable that will be connected to IFOUT. Losses are frequency dependent, so test this at 160MHz (the IF frequency). Use this loss as an offset in all output power/gain calculations.
- 8) Connect this 3dB pad to the EV kit's IFOUT connector and connect a cable from the pad to the spectrum analyzer.
- 9) Set DC supply to +5.0V, and set a current limit of approximately 300mA, if possible. Disable the output voltage and connect the supply to the EV kit (through an ammeter, if desired). Enable the supply. Readjust the supply to get +5.0V at the EV kit. There will be a voltage drop across the ammeter when the mixer is drawing current.
- 10) Select LO1 by connecting LOSEL (TP3) to GND.
- 11) Enable the LO and the RF sources.

Testing the Mixer

Adjust the center and span of the spectrum analyzer to observe the IF output tone at 160MHz. The level should be approximately +0.1dBm (8.1dB conversion gain, 3dB pad loss). There is also a tone at 159MHz, which is due to the LO signal applied to LO2. The amount of suppression between the 160MHz and 159MHz signals is the LO switch isolation. Note that the spectrum analyzer's absolute magnitude accuracy is typically no better than ±1dB. If accuracy is required, use the power meter to measure the absolute single-tone power level.

Disconnect the GND connection to LOSEL. It is pulled high by a pullup resistor on the board, selecting LO2. Observe that the 159MHz signal increases while the 160MHz decreases.

Reconfigure the test setup using a combiner or hybrid to apply two RF signals at RFIN to do a two-tone IP3 measurement, if desired. Terminate the unused LO input in 50Ω .

Detailed Description

The MAX9984 is a high-linearity downconverter integrated with RF and LO baluns, an LO buffer, an IF amplifier, and an SPDT LO input select switch. The EV kit circuit consists mostly of supply-decoupling capacitors, DC-blocking capacitors, an IF balun, and inductive chokes. The MAX9984 EV kit circuit allows for thorough analysis and a simple design-in.

Component Suppliers

SUPPLIER	PHONE	WEBSITE
Coilcraft	800-322-2645	www.coilcraft.com
Digi-Key	800-344-4539	www.digikey.com
Johnson	507-833-8822	www.johnsoncomponents.com
Mini-Circuits	718-934-4500	www.minicircuits.com
Murata	770-436-1300	www.murata.com

Note: Indicate that you are using the MAX9984 when contacting these component suppliers.

Supply-Decoupling Capacitors

Capacitors C2, C7, C8, and C11 are 82pF supply-decoupling capacitors used to filter high-frequency noise. C3, C6, and C9 are larger 0.01µF capacitors used for filtering lower frequency noise on the supply.

DC-Blocking Capacitors

The MAX9984 has internal baluns at the RF and LO inputs. These inputs have almost 0Ω resistance at DC, so DC-blocking capacitors C1, C10, and C12 are used to prevent any external bias from being shunted directly to ground.

LO Bias and IF Bias

Bias currents for the integrated IF amplifier and the LO buffer are set with resistors R1 (953 Ω ±1%) and R2 (619 Ω ±1%), respectively. These values were carefully chosen during factory testing for optimum linearity and minimal supply current. The DC currents can be reduced by increasing the values of R1 and R2, but the device will operate at reduced performance levels (see the *Modifying the EV Kit* section).

Current-Limiting Resistor

Resistor R3 is used for current limiting at the supply, and typically dissipates 60mW.

Tap Network

Capacitor C5 helps to terminate the second-order intermodulation products.

LEXT

The 47nH wire-wound inductor, L3, improves LO-to-IF and RF-to-IF isolation. If isolation is not critical, then this pin can be grounded.

IF±

The MAX9984 employs a differential IF output to offer increased IP2 system performance. The EV kit uses a 4:1 balun to transform the 200Ω differential output impedance to a 50Ω single-ended output for easy bench evaluation. Inductive chokes L1 and L2 provide DC bias to the

IF output amplifier, C13 and C14 for supply filtering, and R3 for current limiting.

As the differential IF outputs are relatively high impedance (200 Ω), they are more susceptible to component parasitics. It is often good practice to relieve the ground plane directly underneath large components to reduce associated shunt-C parasitics.

LOSEL

The EV kit includes a $47k\Omega$ pullup resistor for easy selection of the LO port. Providing a ground at TP3 selects LO1, and leaving TP3 open selects LO2. To drive TP3 from an external source, follow the limits called out in the MAX9984 device data sheet. Logic voltages should not be applied to LOSEL without the +5V supply voltage. Doing so can cause the on-chip ESD diodes to conduct and could damage the device.

Layout Considerations

The MAX9984 evaluation board can be a guide for your board layout. Pay close attention to thermal design and close placement of components to the IC. The MAX9984 package exposed paddle (EP) conducts heat from the device and provides a low-impedance electrical connection to the ground plane. The EP **MUST** be attached to the PC board ground plane with a low-thermal and electrical impedance contact. Ideally, this is achieved by soldering the backside of the package directly to a top metal ground plane on the PC board. Alternatively, the EP can be connected to an internal or bottom-side ground plane using an array of plated vias directly below the EP. The MAX9984 EV kit uses nine evenly spaced, 0.016in-diameter, plated through holes to connect the EP to the lower ground planes.

Depending on the ground-plane spacing, large surface-mount pads in the IF path may need to have the ground plane relieved under them to reduce parasitic shunt capacitance. The layout should minimize the coupling from L1 and L2 to L3.

Modifying the EV Kit

The RF and LO inputs are broadband matched, so there is no need to modify the circuit for use anywhere in the 815MHz to 1000MHz RF range (570MHz to 850MHz LO range).

Retuning for a different IF is as simple as scaling the values of the IF pullup inductors up or down with frequency. The IF output looks like 200Ω differential in parallel with a capacitor. The capacitance is due to the combination of the IC, PC board, and external IF components. The capacitance from the IC is approximately 1pF to ground (0.5pF differential), while that from the PC board and external components is approximately 1pF to ground. The total 2pF of capacitance is resonated out at the frequency of interest by bias inductors L1 and L2. To determine the inductor value use the following equation:

$$f_{IF} = \frac{1}{2\pi\sqrt{LC}}$$

The IF output is tuned for operation at approximately 200MHz, so a 330nH inductor is used. For lower IF frequency (i.e., larger component values), maintain the component's Q value at the cost of larger case size, unless it is unavoidable.

The DC current of the device can be reduced but the performance will be degraded. Reducing the current is accomplished by increasing the values of R1 and R2. Resistor R1 sets the current in the IF amplifier, whereas R2 sets the current in the LO buffer that drives the mixer core.

Setting R1 to 953Ω and R2 to 619Ω results in IF and LO currents of 130mA and 71mA, respectively. Approximately 21mA of additional current is used in other circuits and cannot be reduced. To reduce these adjustable currents in half, double the values of R1 and R2. Doing so reduces the current to approximately 130mA but the gain and IP3 drops approximately 0.3dB and 2.5dB, respectively. Some of the other performance values degrade or improve due to reduced current.

Since the linearity of the device is a result of the cascaded performance of the IF amplifier and the mixer, carefully choose the correct combination of R1 and R2 to produce the highest IP3 at the lowest desired current.

The EV kit can be modified for a 450MHz RF frequency and a 70MHz IF frequency by using the alternative component values listed on page 2. Capacitor CP can be installed using the additional pads next to C1 and C4.

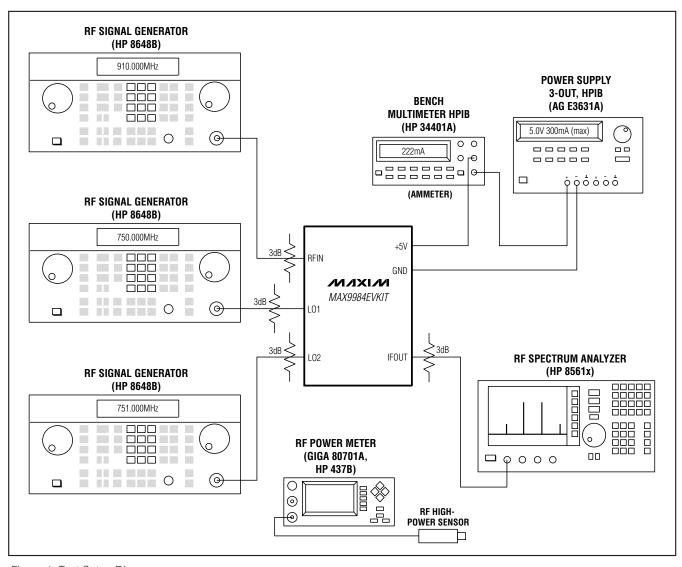


Figure 1. Test Setup Diagram

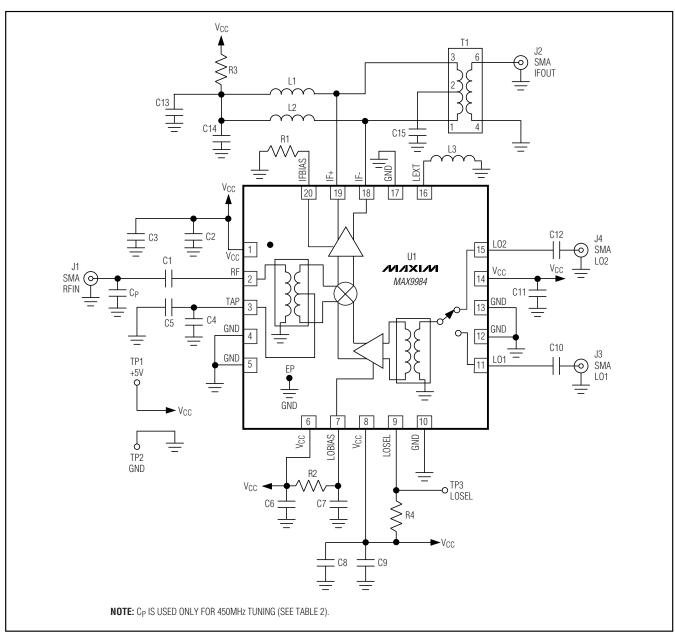


Figure 2. MAX9984 EV Kit Schematic

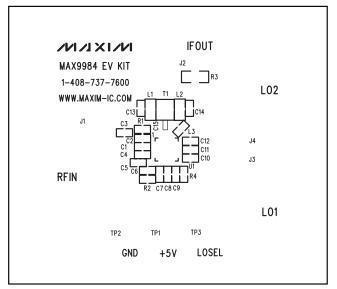


Figure 3. MAX9984 EV Kit PC Board Layout—Top Silkscreen

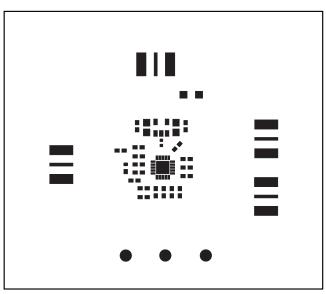


Figure 4. MAX9984 EV Kit PC Board Layout—Top Soldermask

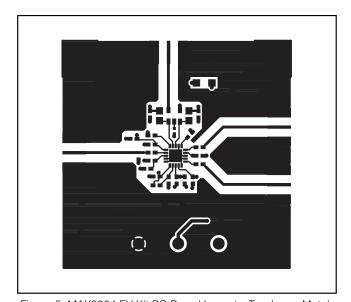


Figure 5. MAX9984 EV Kit PC Board Layout—Top Layer Metal

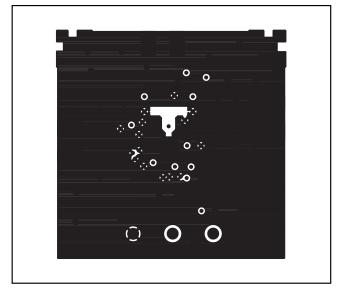


Figure 6. MAX9984 EV Kit PC Board Layout—Inner Layer 2 (GND)

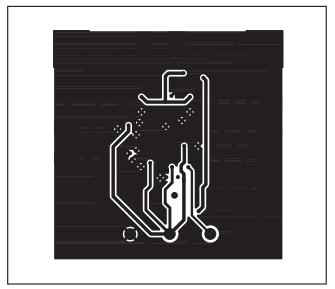


Figure 7. MAX9984 EV Kit PC Board Layout—Inner Layer 3 (Routes)

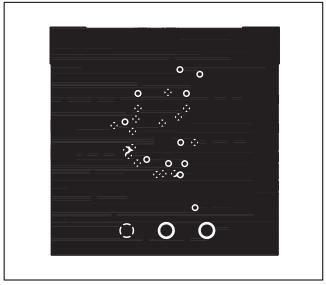


Figure 8. MAX9984 EV Kit PC Board Layout—Bottom Layer (Metal)

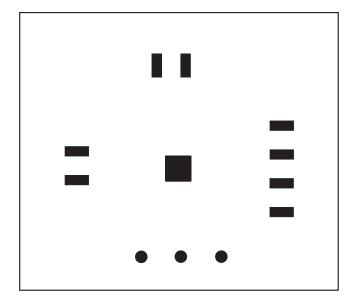


Figure 9. MAX9984 EV Kit PC Board Layout—Bottom Soldermask

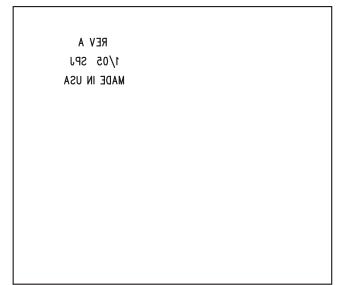


Figure 10. MAX9984 EV Kit PC Board Layout—Bottom Silkscreen

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